

**Features**

- 1.3 mA supply current
- 70 MHz bandwidth
- 2000 V/ $\mu$ s slew rate
- Low bias current, 1  $\mu$ A typical
- 100 mA output current
- Short circuit protected
- Low cost
- Stable with capacitive loads
- Wide supply range  $\pm 5V$  to  $\pm 15V$
- No thermal runaway

**Applications**

- Op amp output current booster
- Cable/line driver
- A/D input buffer
- Low standby current systems

**Ordering Information**

Part No.	Temp. Range	Pkg.	Outline #
EL2001ACN	0°C to +75°C	P-DIP	MDP0031
EL2001CM	0°C to +75°C	20-Lead SOL	MDP0027
EL2001CN	0°C to +75°C	P-DIP	MDP0031

**General Description**

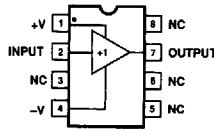
The EL2001 is a low cost monolithic, high slew rate, buffer amplifier. Built using the Elantec monolithic Complementary Bipolar process, this patented buffer has a -3 dB bandwidth of 70 MHz, and delivers 100 mA, yet draws only 1.3 mA of supply current. It typically operates from  $\pm 15V$  power supplies but will work with as little as  $\pm 5V$ .

This high speed buffer may be used in a wide variety of applications in military, video and medical systems. A typical example is a general purpose op amp output current booster where the buffer must have sufficiently high bandwidth and low phase shift at the maximum frequency of the op amp.

Elantec's products and facilities comply with MIL-I-45208A, and other applicable quality specifications. For information on Elantec's processing, see the Elantec document, QRA-1: *Elantec's Processing, Monolithic Integrated Circuits.*

**Connection Diagrams**

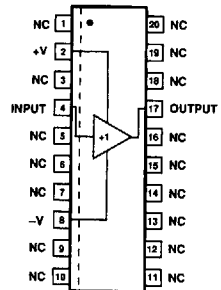
EL2001 DIP Pinout



2001-1

Top View

EL2001 SOL Pinout



2001-2

Top View

Note: Non-designated pins are no connects and are not electrically connected internally.

Manufactured under U.S. Patent No. 4,833,424, 4,827,223 U.K. Patent No. 2217134

# EL2001C

## Low Power, 70 MHz Buffer Amplifier

### Absolute Maximum Ratings

$V_S$	Supply Voltage ( $V+ - V-$ )	$\pm 18V$ or $36V$	$T_A$	Operating Temperature Range	EL2001AC/EL2001C	$0^\circ C$ to $+75^\circ C$
$V_{IN}$	Input Voltage (Note 1)	$\pm 15V$ or $V_S$	$T_J$	Operating Junction Temperature		$150^\circ C$
$I_{IN}$	Input Current (Note 1)	$\pm 50$ mA	$T_{ST}$	Storage Temperature		$-65^\circ C$ to $+150^\circ C$
$P_D$	Power Dissipation (Note 2)	See Curves				
	Output Short Circuit					
	Duration (Note 3)	Continuous				

#### Important Note:

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality Inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore  $T_J = T_C = T_A$ .

Test Level	Test Procedure
I	100% production tested and QA sample tested per QA test plan QCX0002.
II	100% production tested at $T_A = 25^\circ C$ and QA sample tested at $T_A = 25^\circ C$ , $T_{MAX}$ and $T_{MIN}$ per QA test plan QCX0002.
III	QA sample tested per QA test plan QCX0002.
IV	Parameter is guaranteed (but not tested) by Design and Characterization Data.
V	Parameter is typical value at $T_A = 25^\circ C$ for information purposes only.

### Electrical Characteristics $V_S = \pm 15V$ , $R_S = 50\Omega$ , unless otherwise specified

Parameter	Description	Test Conditions			Limits			EL2001AC EL2001C	Units
		$V_{IN}$	Load	Temp	Min	Typ	Max	Test Level	
$V_{OS}$	Offset Voltage EL2001A/EL2001AC	0	$\infty$	$25^\circ C$	-10	2	I	I	mV
				$T_{MIN}, T_{MAX}$	-15		+15	III	mV
	EL2001/EL2001C	0	$\infty$	$25^\circ C$	-30	2	+30	I	mV
				$T_{MIN}, T_{MAX}$	-40		+40	III	mV
$I_{IN}$	Input Current EL2001A/EL2001AC	0	$\infty$	$25^\circ C$	-3	1	+3	I	$\mu A$
				$T_{MIN}, T_{MAX}$	-6		+6	III	$\mu A$
	EL2001/EL2001C	0	$\infty$	$25^\circ C$	-5	1	+5	I	$\mu A$
				$T_{MIN}, T_{MAX}$	-10		+10	III	$\mu A$
$R_{IN}$	Input Resistance	$\pm 12V$	100 $\Omega$	$25^\circ$	1	8		I	M $\Omega$
				$T_{MIN}, T_{MAX}$	0.5			III	M $\Omega$

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# EL2001C

## Low Power, 70 MHz Buffer Amplifier

EL2001C

### Electrical Characteristics $V_S = \pm 15V$ , $R_S = 50\Omega$ , unless otherwise specified — Contd.

Parameter	Description	Test Conditions			Limits			EL2001AC EL2001C	Units
		$V_{in}$	Load	Temp	Min	Typ	Max	Test Level	
$A_{V1}$	Voltage Gain	$\pm 12V$	$\infty$	$25^\circ C$	0.990	0.998		I	V/V
				$T_{MIN}, T_{MAX}$	0.985			III	V/V
$A_{V2}$	Voltage Gain	$\pm 10V$	$100\Omega$	$25^\circ C$	0.83	0.93		I	V/V
				$T_{MIN}, T_{MAX}$	0.80			III	V/V
$A_{V3}$	Voltage Gain with $V_S = \pm 5V$	$\pm 3V$	$100\Omega$	$25^\circ C$	0.82	0.89		I	V/V
				$T_{MIN}, T_{MAX}$	0.79			III	V/V
$V_O$	Output Voltage Swing	$\pm 12V$	$100\Omega$	$25^\circ C$	$\pm 10$	$\pm 11$		I	V
				$T_{MIN}, T_{MAX}$	$\pm 9.5$			III	V
$R_{OUT}$	Output Resistance	$\pm 2V$	$100\Omega$	$25^\circ C$		10	15	I	$\Omega$
				$T_{MIN}, T_{MAX}$			18	III	$\Omega$
$I_{OUT}$	Output Current	$\pm 12V$	(Note 4)	$25^\circ C$	$\pm 100$	$\pm 160$		I	mA
				$T_{MIN}, T_{MAX}$	$\pm 95$			III	mA
$I_S$	Supply Current	0	$\infty$	$25^\circ C$		1.3	2.0	I	mA
				$T_{MIN}, T_{MAX}$			2.5	III	mA
PSRR	Supply Rejection, (Note 5)	0	$\infty$	$25^\circ C$	60	75		I	dB
				$T_{MIN}, T_{MAX}$	50			III	dB
$t_r$	Rise Time	0.5V	$100\Omega$	$25^\circ C$		4.2		V	ns
$t_d$	Propagation Delay	0.5V	$100\Omega$	$25^\circ C$		2.0		V	ns
SR	Slew Rate, (Note 6)	$\pm 10V$	$100\Omega$	$25^\circ C$	1200	2000		IV	V/ $\mu s$

Note 1: If the input exceeds the ratings shown (or the supplies) or if the input to output voltage exceeds  $\pm 7.5V$  then the input current must be limited to  $\pm 50$  mA. See the applications section for more information.

Note 2: The maximum power dissipation depends on package type, ambient temperature and heat sinking. See the characteristic curves for more details.

Note 3: A heat sink is required to keep the junction temperature below the absolute maximum when the output is short circuited.

Note 4: Force the input to  $+12V$  and the output to  $+10V$  and measure the output current. Repeat with  $-12V_{IN}$  and  $-10V$  on the output.

Note 5:  $V_{OS}$  is measured at  $V_{S+} = +4.5V$ ,  $V_{S-} = -4.5V$  and at  $V_{S+} = +18V$ ,  $V_{S-} = -18V$ . Both supplies are changed simultaneously.

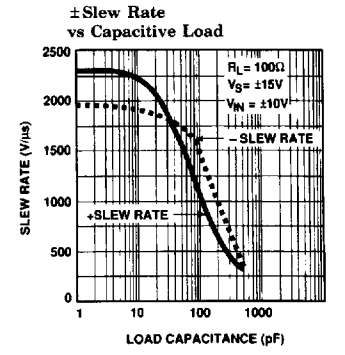
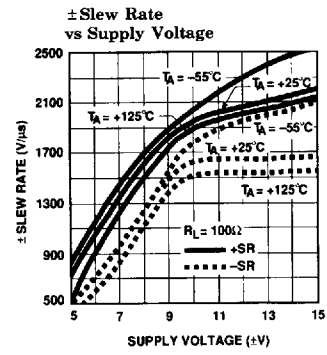
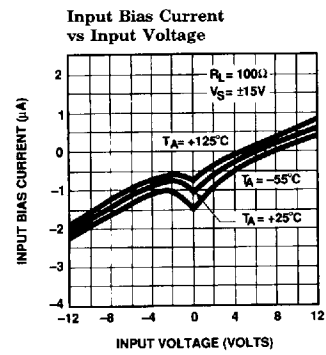
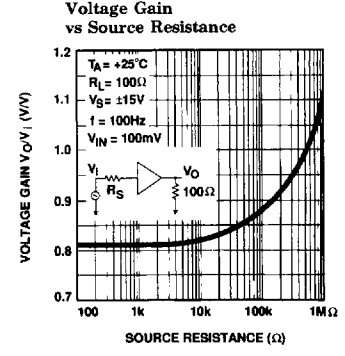
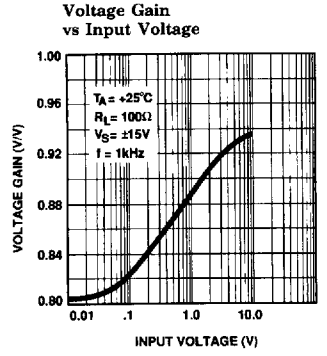
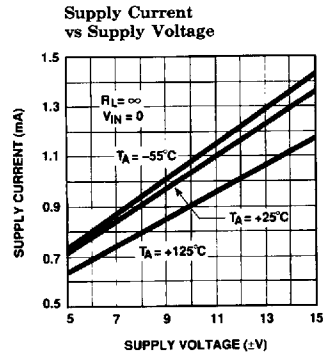
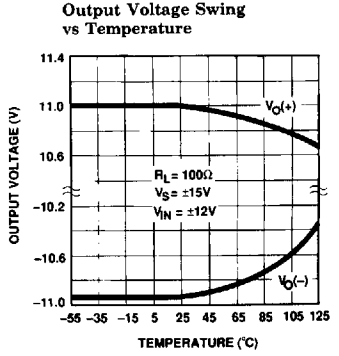
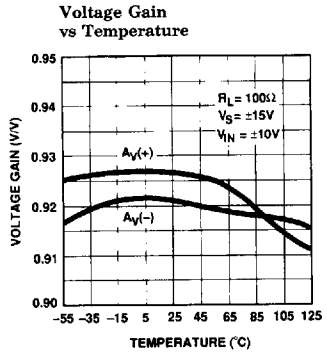
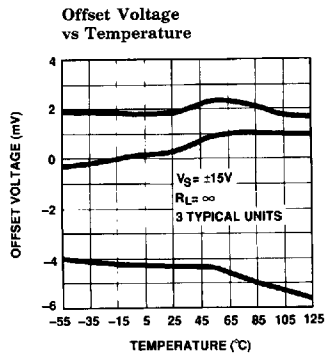
Note 6: Slew rate is measured between  $V_{OUT} = +5V$  and  $-5V$ .

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# EL2001C

## Low Power, 70 MHz Buffer Amplifier

### Typical Performance Curves

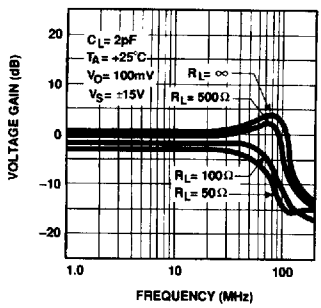


# EL2001C

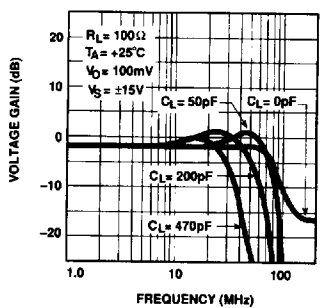
## Low Power, 70 MHz Buffer Amplifier

### Typical Performance Curves — Contd.

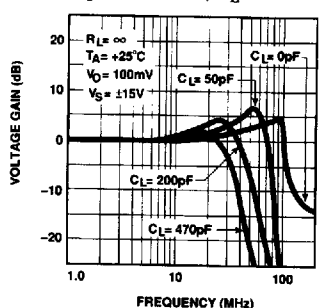
**Voltage Gain vs Frequency for Various Resistive Loads**



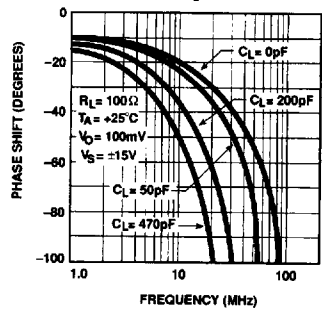
**Voltage Gain vs Frequency for Various Capacitive Loads; RL = 100Ω**



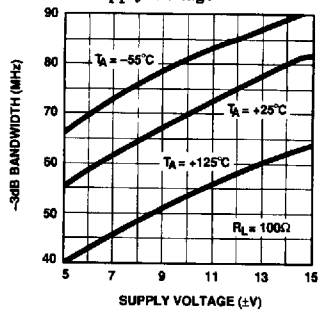
**Voltage Gain vs Frequency for Various Capacitive Loads; RL = ∞**



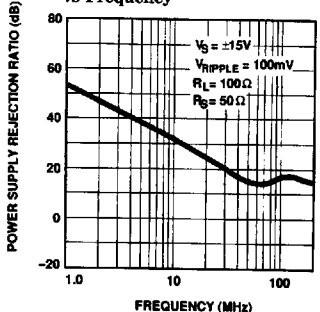
**Phase Shift vs Frequency for Various Capacitive Loads**



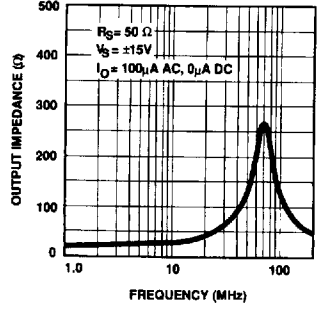
**-3 dB Bandwidth vs Supply Voltage**



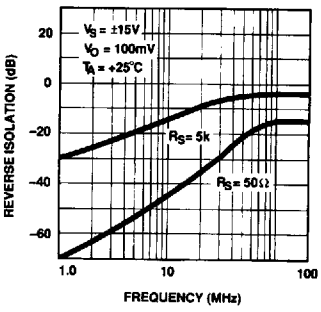
**Power Supply Rejection Ratio vs Frequency**



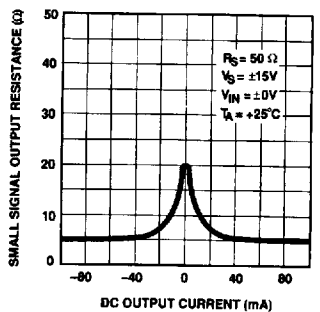
**Output Impedance vs Frequency**



**Reverse Isolation vs Frequency**



**Small Signal Output Resistance vs Output Current**



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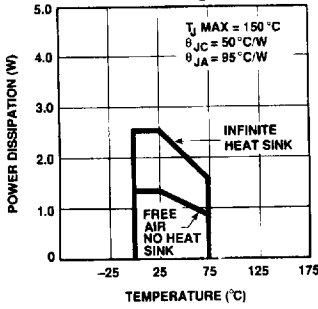
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# EL2001C

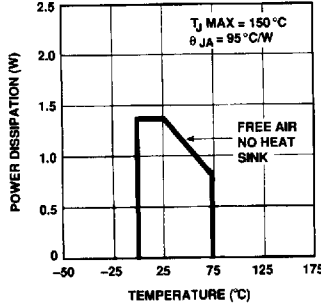
## Low Power, 70 MHz Buffer Amplifier

### Typical Performance Curves — Contd.

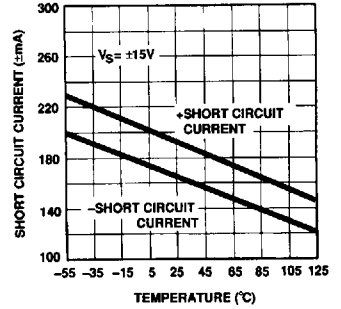
8-Lead Plastic DIP  
Maximum Power Dissipation  
vs Ambient Temperature



20-Lead SOL  
Maximum Power Dissipation  
vs Ambient Temperature

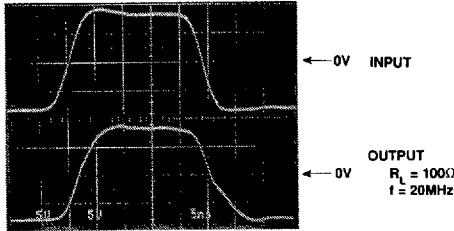


Short Circuit Current  
vs Temperature



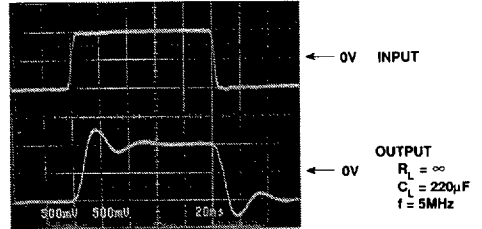
2001-6

Large Signal Response



2001-7

Small Signal Response

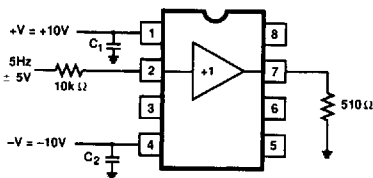


2001-8

# EL2001C

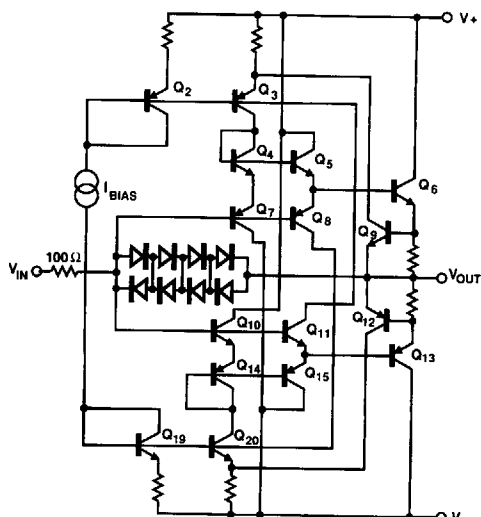
## Low Power, 70 MHz Buffer Amplifier

### Burn-In Circuit



2001-9

### Simplified Schematic



2001-10

### Application Information

The EL2001 is a monolithic buffer amplifier built on Elantec's proprietary dielectric isolation process that produces NPN and PNP transistors with essentially identical DC and AC characteristics. The EL2001 takes full advantage of the complementary process with a unique circuit topology.

Elantec has applied for two patents based on the EL2001's topology. The patents relate to the base drive and feedback mechanism in the buffer. This feedback makes 2000 V/ $\mu$ s slew rates with 100 $\Omega$  loads possible with very low supply current.

### Power Supplies

The EL2001 may be operated with single or split supplies with total voltage difference between 10V ( $\pm 5$ V) and 36V ( $\pm 18$ V). It is not necessary to use equal split value supplies. For example  $-5$ V and  $+12$ V would be excellent for signals from  $-2$ V to  $+9$ V.

Bypass capacitors from each supply pin to ground are highly recommended to reduce supply ringing and the interference it can cause. At a minimum, 1  $\mu$ F tantalum capacitor with short leads should be used for both supplies.

### Input Characteristics

The input to the EL2001 looks like a resistance in parallel with about 3.5 picofarads in addition to a DC bias current. The DC bias current is due to the mismatch in beta and collector current between the NPN and PNP transistors connected to the input pin. The bias current can be either positive or negative. The change in input current with input voltage ( $R_{IN}$ ) is affected by the output load, beta and the internal boost.  $R_{IN}$  can actually appear negative over portions of the input range; typical input current curves are shown in the characteristic curves. Internal clamp diodes from the input to the output are provided. These diodes protect the transistor base emitter junctions and limit the boost current during slew to avoid saturation of internal transistors. The diodes begin conduction at about  $\pm 2.5$ V input to output differential. When that happens the input resistance drops dramatically. The diodes are rated at 50 mA. When conducting they have a series resistance of about 20 $\Omega$ . There is also 100 $\Omega$  in series with the input that limits input current. Above  $\pm 7.5$ V differential input to output, additional series resistance should be added.

### Source Impedance

The EL2001 has good input to output isolation. When the buffer is not used in a feedback loop, capacitive and resistive sources up to 1 Meg present no oscillation problems. Care must be used in board layout to minimize output to input coupling. CAUTION: When using high source impedances ( $R_S > 100$  k $\Omega$ ), significant gain errors can be observed due to output offset, load resistor, and the action of the boost circuit. See typical performance curves.

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# EL2001C

## Low Power, 70 MHz Buffer Amplifier

### EL2001C Macromodel

\*Connections: + input

*				+ Vsupply
*				- Vsupply
*				output
*				

.subckt M2001 2 1 4 7

\* Input Stage

e1 10 0 2 0 1.0

r1 10 0 1K

rh 10 11 150

ch 11 0 9pF

rc 11 12 100

cc 12 0 4pF

e2 13 0 12 0 1.0

\* Output stage

q1 4 13 14 qp

q2 1 13 15 qn

q3 1 14 16 qn

q4 4 15 19 qp

r2 16 7 1

r3 19 7 1

i1 1 14 0.9mA

i2 15 4 0.9mA

\* Bias Current

iin+ 2 0 1uA

\* Models

.model qn npn(is= 5e-15 bf= 150 rb= 200 ptf= 45 tf= 0.1nS)

.model qp pnp(is= 5e-15 bf= 150 rb= 200 ptf= 45 tf= 0.1nS)

.ends

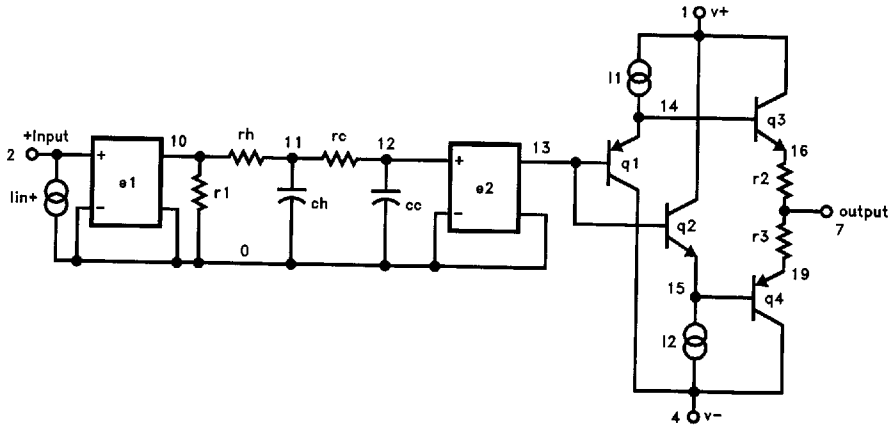


# EL2001C

Low Power, 70 MHz Buffer Amplifier

EL2001C

## EL2001C Macromodel — Contd.



2001-11

2

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## Soldering Packages to PC Boards

### DIP Packages

**Wave soldering** is recommended for DIP packages. Solder plated boards are recommended. Rosin mildly activated (RMA) flux is needed. Wave soldering using a dual wave system at  $250^{\circ}\text{C} \pm 10^{\circ}\text{C}$  for two seconds per wave is preferable. Thorough cleaning of boards after soldering is required.

**Hand soldering**, Elantec's DIP packages will survive a peak temperature of  $300^{\circ}\text{C}$  (at leads) for a maximum period of 10 seconds.

### Surface Mount Packages

Wave soldering and vapor phase or infrared (IR) reflow can be used for soldering surface mount packages to PC boards. Solder plated boards are recommended for wave soldering and vapor phase or IR reflow methods.

**Wave Soldering:** Adhesive is used to hold components on the boards during wave soldering. Place components on the board and cure adhesive

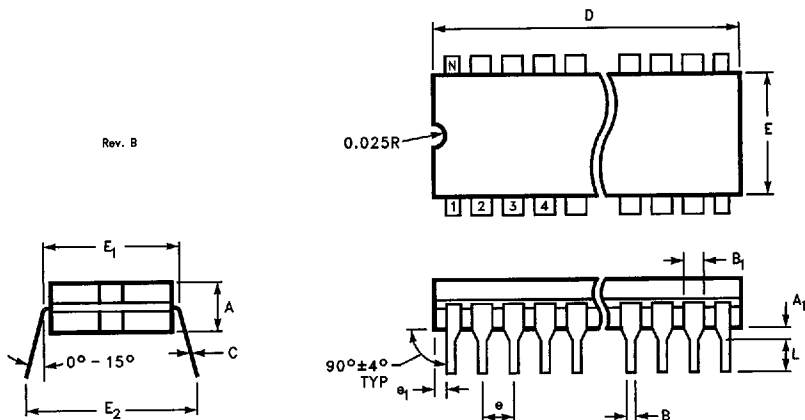
before wave soldering. Rosin mildly activated (RMA) flux or organic flux is needed. Wave soldering using a dual wave system at  $250^{\circ}\text{C} \pm 10^{\circ}\text{C}$  for a maximum of two seconds per wave is preferable. Thorough cleaning of boards after soldering is required.

**Reflow Soldering:** Screen solder paste on board and attach components to board. Solder paste with RMA flux is recommended. Bake boards at  $65^{\circ}\text{C}$ – $90^{\circ}\text{C}$  for 15 minutes. Preheat boards to within  $60^{\circ}\text{C}$ – $70^{\circ}\text{C}$  of the solder temperature. To reflow solder paste with vapor phase method, the solder paste temperature must be maintained at or above  $200^{\circ}\text{C}$  for at least 30 seconds. The components temperature can not exceed  $215^{\circ}\text{C}$ . For the IR reflow method, the solder paste temperature must be maintained at or above  $200^{\circ}\text{C}$  for at least 30 seconds. The components temperature can not exceed  $220^{\circ}\text{C}$ . The temperature/time ramp-up during vapor phase or IR reflow shall be no greater than  $2^{\circ}\text{C}/\text{sec}$ .

**Hand soldering**, Elantec's surface mount packages will survive a peak temperature of  $260^{\circ}\text{C}$  (at leads) for a maximum period of 10 seconds.

# Package Outlines

Rev. B



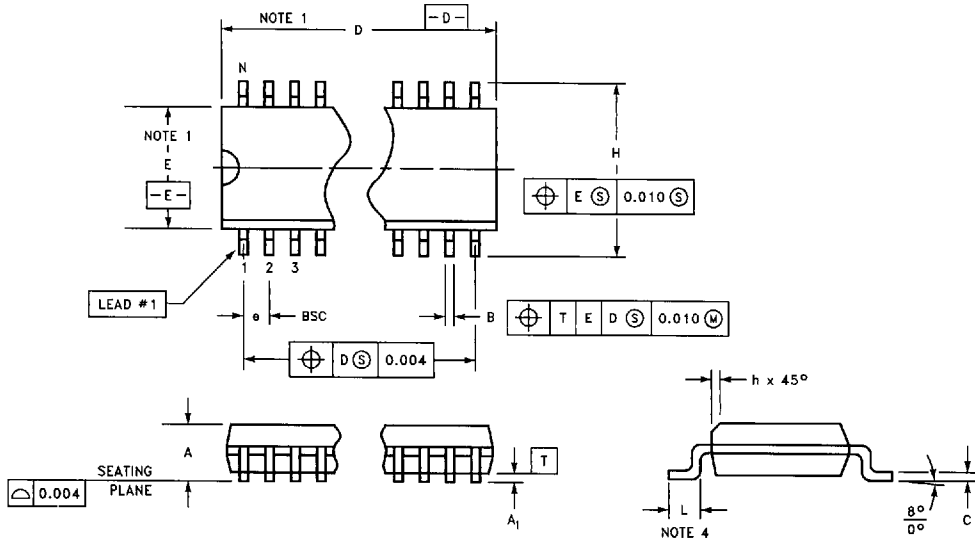
## MDP0016 Rev. B

### CerDIP Package

Lead Finish (Coml)—Tin Plate or Hot Solder DIP

Lead Finish (Mil)—Hot Solder DIP

Common Dimensions	Min	Max	Min	Max	Min	Max	Min	Max
A	0.140	0.160	0.140	0.160	0.140	0.160	0.140	0.160
A <sub>1</sub>	0.115	0.055	0.020	0.050	0.015	0.060	0.020	0.050
B	0.016	0.023	0.016	0.021	0.014	0.026	0.016	0.021
B <sub>1</sub>	0.050	0.065	0.050	0.060	0.038	0.068	0.050	0.060
C	0.008	0.012	0.008	0.012	0.008	0.018	0.008	0.012
D	0.375	0.395	0.760	0.785	0.940	0.960	1040.925	1.060
E	0.245	0.265	0.220	0.291	0.220	0.310	0.2780	0.298
E <sub>1</sub>	0.300	0.320	0.300	0.320	0.290	0.320	0.300	0.320
E <sub>2</sub>	0.340	0.390	0.340	0.390	0.360	0.410	0.340	0.390
e	0.090	0.110	0.090	0.110	0.090	0.110	0.090	0.110
e <sub>1</sub>	0.020	0.055	0.078	0.098	0.068	0.098	0.078	0.098
L	0.125	0.150	0.125	0.150	0.125	0.150	0.130	0.150
N	8-Lead		14-Lead		18-Lead		20-Lead	



REV. C

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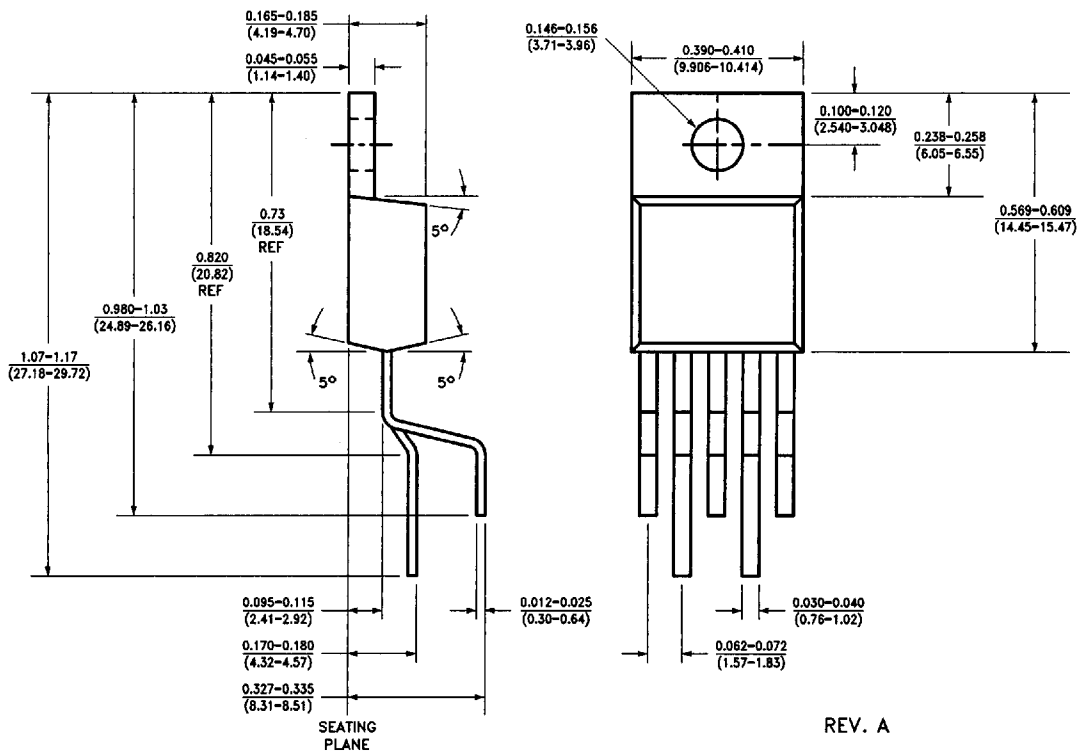
- Note 1: These dimensions do not include mold flash or protrusions. Mold flash protrusion shall not exceed .006" on any side.
- Note 2: SO-8, SO-14, SO-16 packages are narrow body (0.150").
- Note 3: Dimensions and tolerancing per ANSI Y14.5M-1982.
- Note 4: Flat area of lead foot.
- Note 5: SOL-24T2 (thermal package) has 2 fused leads on each side of package.
- Note 6: SOL-20T (thermal package) has 4 fused leads on each side of package.
- Note 7: SOL-28T contains a thermal metal slug.

**MDP0027 Rev. C**  
**Package Outline—SOIC**  
 Lead Finish—Solder Plate

Symbol	Lead Count													
	SOL-28		SOL-20		SOL-16		SO-16		SO-14		SO-8		SOL-24	
	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max
A	0.096	0.104	0.096	0.104	0.096	0.104	0.061	0.068	0.061	0.068	0.061	0.068	0.096	0.104
A <sub>1</sub>	0.004	0.011	0.004	0.011	0.004	0.011	0.004	0.010	0.004	0.010	0.004	0.010	0.004	0.011
B	0.014	0.019	0.014	0.019	0.014	0.019	0.014	0.019	0.014	0.019	0.014	0.019	0.014	0.019
C	0.009	0.012	0.009	0.012	0.009	0.012	0.008	0.010	0.008	0.010	0.008	0.010	0.009	0.012
D	0.696	0.712	0.498	0.510	0.397	0.430	0.386	0.394	0.337	0.344	0.189	0.196	0.598	0.614
E	0.291	0.299	0.291	0.299	0.291	0.299	0.150	0.157	0.150	0.157	0.150	0.157	0.291	0.299
e	0.050 BSC		0.050 BSC		0.050 BSC		0.050 BSC		0.050 BSC		0.050 BSC		0.050 BSC	
H	0.398	0.414	0.398	0.414	0.398	0.414	0.230	0.244	0.230	0.244	0.230	0.244	0.398	0.414
h	0.010	0.016	0.010	0.016	0.010	0.016	0.010	0.016	0.010	0.016	0.010	0.016	0.010	0.016
L	0.016	0.024	0.016	0.024	0.016	0.024	0.016	0.024	0.016	0.024	0.016	0.024	0.016	0.024

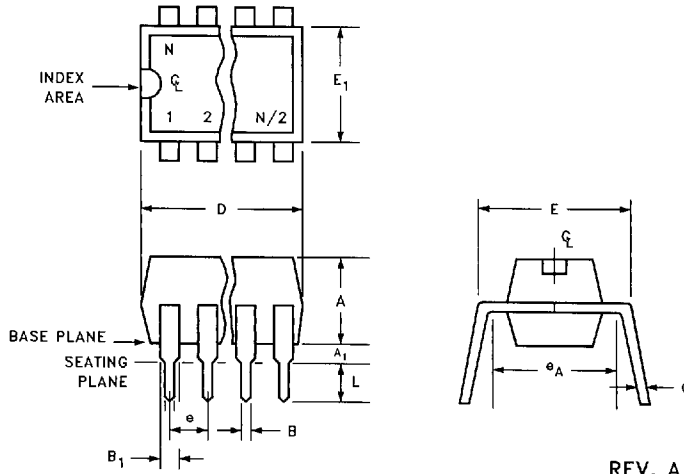
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**Package Outlines**



**MDP0028 Rev. A**  
**5-Lead TO-220**  
 Lead Finish—Solder Plate

REV. A



REV. A

MDP0031 Rev. A  
Plastic Package  
Lead Finish—Hot Solder DIP

Common Dimensions	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max
A <sub>1</sub>	0.020	0.040	0.020	0.040	0.020	0.040	0.020	0.040	0.020	0.040
A	0.125	0.145	0.125	0.145	0.125	0.145	0.125	0.145	0.125	0.145
B	0.016	0.020	0.016	0.020	0.016	0.020	0.016	0.020	0.015	0.021
B <sub>1</sub>	0.050	0.070	0.050	0.070	0.050	0.070	0.050	0.070	0.050	0.070
C	0.008	0.012	0.008	0.012	0.008	0.012	0.008	0.012	0.008	0.012
D	0.350	0.385	0.745	0.755	0.745	0.755	0.875	0.905	0.925	1.045
E	0.295	0.320	0.295	0.320	0.295	0.320	0.295	0.320	0.295	0.320
E <sub>1</sub>	0.245	0.255	0.245	0.255	0.245	0.255	0.245	0.255	0.245	0.255
e	0.100 Typ		0.100 Typ		0.100 Typ		0.100 Typ		0.100 Typ	
e <sub>A</sub>	0.300 Ref		0.300 Ref		0.300 Ref		0.300 Ref		0.300 Ref	
L	0.115	0.135	0.115	0.135	0.115	0.135	0.115	0.135	0.115	0.135
N	8		14		16		18		20	

Note: Package outline exclusive of any mold flashes. Mold flash protrusion shall not exceed 0.006" on any side.